

MOSFETs Silicon N-channel MOS (U-MOSIX-H)

TK3R1E04PL

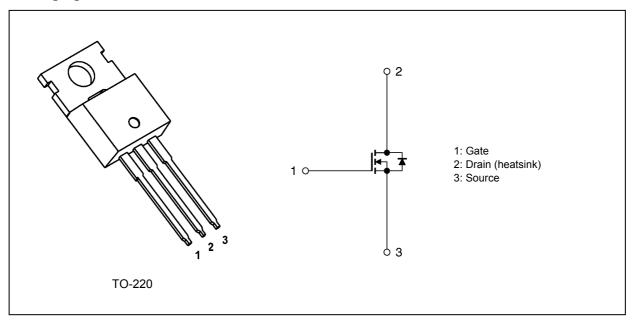
1. Applications

- High-Efficiency DC-DC Converters
- Switching Voltage Regulators
- · Motor Drivers

2. Features

- (1) High-speed switching
- (2) Small gate charge: $Q_{SW} = 17.5 \text{ nC (typ.)}$
- (3) Small output charge: $Q_{oss} = 42 \text{ nC (typ.)}$
- (4) Low drain-source on-resistance: $R_{DS(ON)} = 2.5 \text{ m}\Omega$ (typ.) ($V_{GS} = 10 \text{ V}$)
- (5) Low leakage current: $I_{DSS} = 10 \mu A \text{ (max) (V}_{DS} = 40 \text{ V)}$
- (6) Enhancement mode: V_{th} = 1.4 to 2.4 V (V_{DS} = 10 V, I_{D} = 0.5 mA)

3. Packaging and Internal Circuit





4. Absolute Maximum Ratings (Note) (Ta = 25 °C unless otherwise specified)

Characteristics			Symbol	Rating	Unit
Drain-source voltage			V_{DSS}	40	V
Gate-source voltage			V _{GSS}	±20	
Drain current (DC)	(T _c = 25 °C)	(Note 1)	I _D	100	Α
Drain current (DC)	(Silicon limit)	(Note 1), (Note 2)	I _D	128	
Drain current (pulsed)	(t = 100 μs)	(Note 1)	I _{DP}	400	
Power dissipation	(T _c = 25 °C)		P_{D}	87	W
Single-pulse avalanche energy		(Note 3)	E _{AS}	35	mJ
Single-pulse avalanche current		(Note 3)	I _{AS}	100	Α
Channel temperature			T _{ch}	175	℃
Storage temperature			T _{stg}	-55 to 175	℃
Mounting torque			TOR	0.6	N · m

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

5. Thermal Characteristics

Characteristics	Symbol	Max	Unit
Channel-to-case thermal resistance $(T_c = 25 ^{\circ}\text{C})$	R _{th(ch-c)}	1.72	°C/W
Channel-to-ambient thermal resistance (T _a = 25 °C)	R _{th(ch-a)}	83.3	

Note 1: Ensure that the channel temperature does not exceed 175 °C.

Note 2: Limited 100 A by package capability.

Note 3: V_{DD} = 32 V, T_{ch} = 25 °C (initial), L = 2.7 μH , I_{AS} = 100 A

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.



6. Electrical Characteristics

6.1. Static Characteristics (T_a = 25 °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current	I _{GSS}	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±0.1	μА
Drain cut-off current	I _{DSS}	V _{DS} = 40 V, V _{GS} = 0 V			10	
Drain-source breakdown voltage	V _{(BR)DSS}	$I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$	40			V
Drain-source breakdown voltage (Note 4)	V _{(BR)DSX}	$I_D = 10 \text{ mA}, V_{GS} = -20 \text{ V}$	25	_		
Gate threshold voltage	V_{th}	V _{DS} = 10 V, I _D = 0.5 mA	1.4	_	2.4	
Drain-source on-resistance	R _{DS(ON)}	$V_{GS} = 4.5 \text{ V}, I_D = 30 \text{ A}$	_	3.0	3.8	mΩ
		V _{GS} = 10 V, I _D = 41 A		2.5	3.1	

Note 4: If a reverse bias is applied between gate and source, this device enters $V_{(BR)DSX}$ mode. Note that the drain-source breakdown voltage is lowered in this mode.

6.2. Dynamic Characteristics (T_a = 25 °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input capacitance	C _{iss}	V _{DS} = 20 V, V _{GS} = 0 V, f = 1 MHz	_	4670	_	pF
Reverse transfer capacitance	C _{rss}		_	70	_	
Output capacitance	C _{oss}		_	1000	_	
Gate resistance	r _g	_	_	2.2	_	Ω
Switching time (rise time)	t _r	See Fig. 6.2.1	_	12	_	ns
Switching time (turn-on time)	t _{on}		_	28	_	
Switching time (fall time)	t _f		_	27	_	
Switching time (turn-off time)	t _{off}		_	83	_	

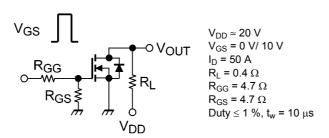


Fig. 6.2.1 Switching Time Test Circuit

6.3. Gate Charge Characteristics (T_a = 25 °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Total gate charge (gate-source plus	Q_g	$V_{DD} \approx 20 \text{ V}, V_{GS} = 10 \text{ V}, I_{D} = 50 \text{ A}$	_	63.4		nC
gate-drain)		$V_{DD} \approx 20 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{D} = 50 \text{ A}$	_	29.7		
Gate-source charge 1	Q _{gs1}	$V_{DD} \approx 20 \text{ V}, V_{GS} = 10 \text{ V}, I_{D} = 50 \text{ A}$	_	16.8		
Gate-drain charge	Q_{gd}		_	8.9	_	
Gate switch charge	Q_{SW}		_	17.5		
Output charge	Q _{oss}	V _{DS} = 20 V, V _{GS} = 0 V, f = 1 MHz	_	42	_	



6.4. Source-Drain Characteristics ($T_a = 25$ °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Reverse drain current (pulsed) (Note 5)	I _{DRP} (t = 100 μs)	_	1	ı	400	Α
Diode forward voltage	V_{DSF}	I _{DR} = 100 A, V _{GS} = 0 V			-1.5	V
Reverse recovery time		V _R = 20 V, I _{DR} = 25 A,		50	_	ns
Reverse recovery charge	Q _{rr}	$V_{GS} = 0 \text{ V}, -dI_{DR}/dt = 100 \text{ A/}\mu\text{s}$		50	_	nC

Note 5: Ensure that the channel temperature does not exceed 175 °C.

7. Marking

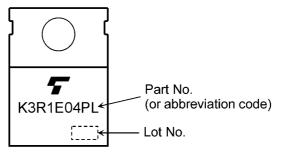


Fig. 7.1 Marking

8. Characteristics Curves (Note)

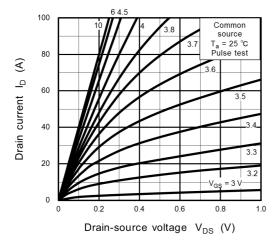


Fig. 8.1 I_D - V_{DS}

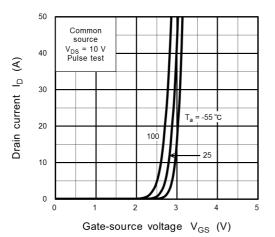


Fig. 8.3 $I_D - V_{GS}$

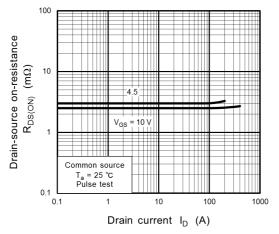


Fig. 8.5 R_{DS(ON)} - I_D

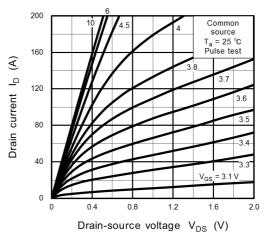


Fig. 8.2 I_D - V_{DS}

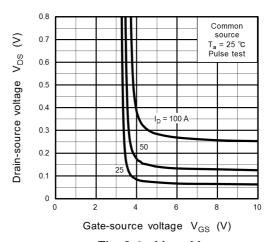


Fig. 8.4 V_{DS} - V_{GS}

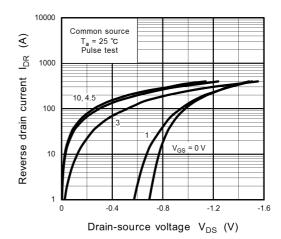


Fig. 8.6 IDR - VDS

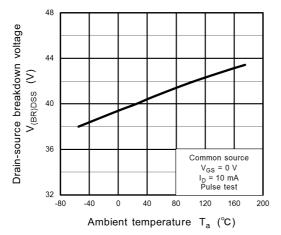


Fig. 8.7 V_{(BR)DSS} - T_a

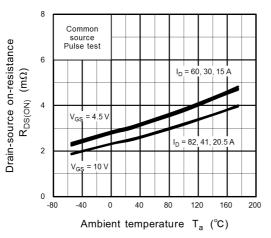


Fig. 8.9 R_{DS(ON)} - T_a

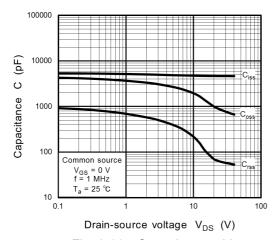


Fig. 8.11 Capacitance - V_{DS}

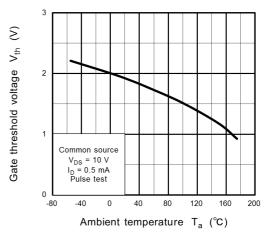


Fig. 8.8 V_{th} - T_a

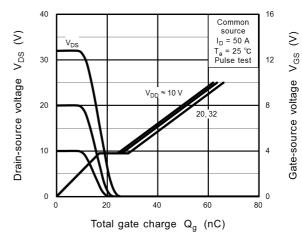


Fig. 8.10 Dynamic Input/Output Characteristics

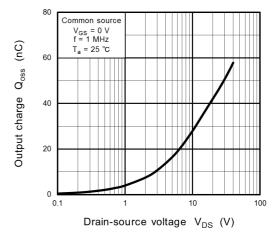


Fig. 8.12 Qoss - VDS

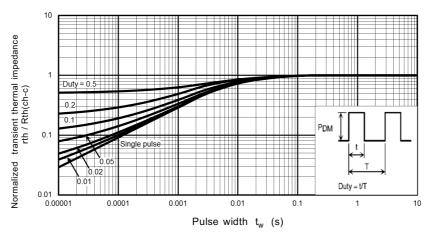


Fig. 8.13 $r_{th}/R_{th(ch-c)} - t_w$ (Guaranteed Maximum)

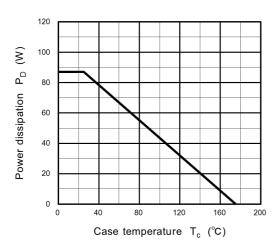


Fig. 8.14 P_D - T_c (Guaranteed Maximum)

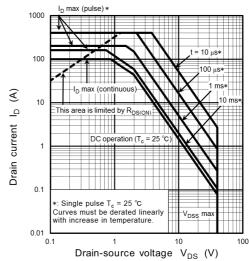


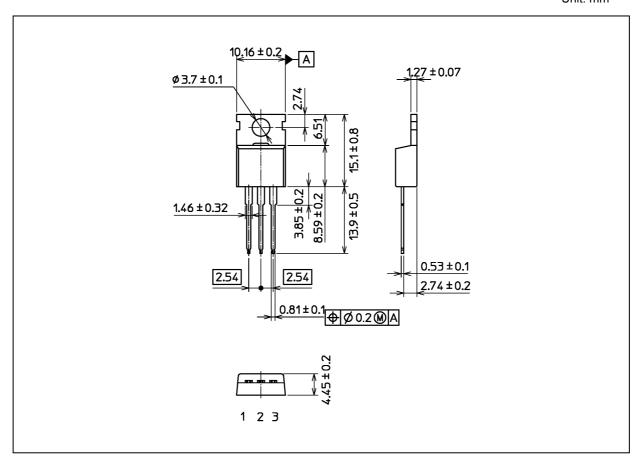
Fig. 8.15 Safe Operating Area (Guaranteed Maximum)

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



Package Dimensions

Unit: mm



Weight: 1.93 g (typ.)

Package Name(s)
TOSHIBA: 2-10X1A
Nickname: TO-220



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